Diode Semiconductor Device - Page 1 of 1



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	osure Material:
Glas	
	erall Length:
	00 inches
	ninal Length:
	75 inches
	erall Diameter:
0.14	15 inches
Fun	ction For Which Designed:
Zen	er diode
Mou	unting Method:
Terr	ninal
Feat	tures Provided:
Herr	metically sealed case
Sem	niconductor Material:
Silic	on
Volt	age Rating In Volts Per Characteristic:
30.0) regulator voltage
Volt	age Tolerance In Percent:
-5.0/	/+5.0
Cur	rent Rating Per Characteristic:
40.0	00 milliamperes all primaries horsepower metric
Pow	ver Rating Per Characteristic:
5.0 v	watts small-signal input power, common-collector preset
Мах	timum Operating Tempurature Per Measurement Point:
175.	.0 degrees celsius ambient air
Terr	ninal Type And Quantity:
2 un	insulated wire lead
She	If Life:
N/a	
Unit	t Of Measure:
Dem	nilitarization:
No	
Fiig	:
	0a0